











SBOS830E - SEPTEMBER 2017-REVISED MAY 2019

OPA189, OPA2189

OPAx189 Precision, Lowest-Noise 36-V, Zero-Drift, 14-MHz MUX-Friendly, Rail-to-Rail Output, Operational Amplifiers

1 Features

• Ultra-high precision:

- Zero-drift: 0.005 μ V/°C (OPA189)

– Ultra-low offset voltage: 3 μ V maximum

(OPA189)

Excellent dc precision:

- CMRR: 168 dB

Open-loop gain: 170 dB

Low noise:

- e_n at 1 kHz: 5.2 nV/ \sqrt{Hz}

- 0.1-Hz to 10-Hz noise: 0.1 μV_{PP}

• Excellent dynamic performance:

Gain bandwidth: 14 MHz

Slew rate: 20 V/µs

Fast settling: 10-V step, 0.01% in 1.1 μs

Robust design:

MUX-friendly inputs

- RFI/EMI filtered inputs

Wide supply range: 4.5 V to 36 V

Quiescent current: 1.7 mA (maximum)

• Rail-to-rail output

Input includes negative rail

2 Applications

- Precision multichannel systems
- Bridge amplifier
- Strain gauges
- Resistance temperature detectors

Temperature measurement

3 Description

The OPA189 and OPA2189 (OPAx189) precision operational amplifiers are ultra-low noise, fast-settling, zero-drift devices that provide rail-to-rail output operation and feature a unique MUX-friendly architecture and controlled start-up system. These features and excellent ac performance, combined with only 0.4 µV of offset voltage and 0.005µV/°C of drift over temperature for the single-channel version, make the OPAx189 a great choice for precision instrumentation, signal measurement, and active filtering applications. Moreover, the MUX-friendly input architecture prevents inrush current when applying large input differential voltages, which improves settling performance in multichannel systems, all while providing robust ESD protection during shipment, handling, and assembly.

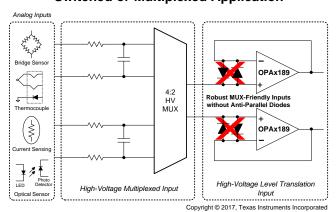
All versions are specified from -40°C to +125°C.

Device Information⁽¹⁾

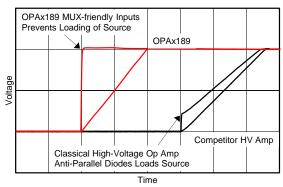
PART NUMBER	PACKAGE	BODY SIZE (NOM)
	SOIC (8)	4.90 mm × 3.90 mm
OPA189	SOT-23 (5)	2.90 mm × 1.60 mm
	VSSOP (8)	3.00 mm × 3.00 mm
	SOIC (8)	4.90 mm × 3.90 mm
OPA2189	VSSOP (8) (preview)	3.00 mm × 3.00 mm

 For all available packages, see the package option addendum at the end of the data sheet.

OPAx189 Preserves R-C Settling Performance in a Switched or Multiplexed Application



OPAx189 MUX-Friendly Input Settles Quickly and Maintains High Input Impedance When Switched



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4 Revision History

Changes from Revision D (December 2018) to Revision E

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (November 2017) to Revision B	Page
First release of production-data sheet for OPA189IDGK	
Changes from Revision B (October 2018) to Revision C	Page
Added OPA189 long-term drift and OPA2189 channel separation curves	16
Changed Maximum Output Voltage Amplitude vs Frequency to reflect undistorted operating range	
Added crosstalk for OPA2189ID	9
Added input offset current for OPA2189ID	8
Added input bias current for OPA2189ID	
Changed OPA2189 SOIC (D) package from preview to production data	
Changes from Revision C (October 2018) to Revision D	Page
Added new Figure 39, OPA2189 Long-Term Drift	17
Changed Figure 9, Closed-Loop Gain vs Frequency, for clarity	
Changed Figure 8, Open-Loop Gain and Phase vs Frequency, for clarity	
Changed Figure 4, Input Offset Current Production Distribution, to show updated data	
Changed Figure 3, Input Bias Current Production Distribution, to show updated data	
Changed OPA189 SOT-23 (DBV) package from preview to production data (active)	······································

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Ch	nanges from Original (September 2017) to Revision A	Page
•	First release of production-data sheet for OPA189ID device	

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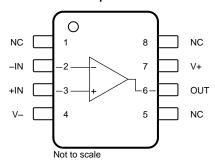
5 Device Comparison Table

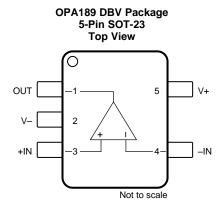
PRODUCT	FEATURES
OPA188	25-μV, 0.085-μV/°C, 8.8-nV/√Hz, Rail-to-Rail Output, 36-V, Zero-Drift CMOS
OPA388	5-μV, 0.05-μV/°C, 7-nV/√Hz, 10-MHz, <i>True</i> Rail-to-Rail Input/Output, 5.5-V, Zero-Drift CMOS
OPA333	10-μV, 0.05-μV/°C, 25-μA, Rail-to-Rail Input/Output, 5.5-V, Zero-Drift CMOS
OPA192	25-μV, 0.8-μV/°C, 1-mA, 10-MHz, Rail-to-Rail Input/Output, 36-V, e-Trim CMOS
OPA140	120-µV, 10-MHz, 5.1-nV/√Hz, 36-V JFET Input Industrial Op Amp
OPA209	2.2-nV/√Hz, 150-μV, 18-MHz, 36-V Bipolar Op Amp in SOT-23 package



6 Pin Configuration and Functions

OPA189 D and DGK Packages 8-Pin SOIC, 8-Pin VSSOP Top View

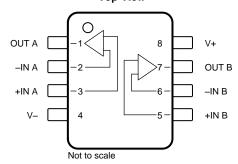




Pin Functions: OPA189

	PIN				
NAME	D (SOIC) DGK (VSSOP)	DBV (SOT-23)	I/O	DESCRIPTION	
-IN	2	4	I	Inverting input	
+IN	3	3	I	Noninverting input	
NC	1, 5, 8	_	_	No internal connection (can be left floating)	
OUT	6	1	0	Output	
V-	4	2	_	Negative (lowest) power supply	
V+	7	5	_	Positive (highest) power supply	

OPA2189 D and DGK (preview) Packages 8-Pin SOIC, 8-Pin VSSOP Top View



Pin Functions: OPA2189

PIN				
NAME	NO.	I/O	DESCRIPTION	
−IN A	2	I	Inverting input channel A	
+IN A	3	I	Noninverting input channel A	
–IN B	6	I	overting input channel B	
+IN B	5	I	Noninverting input channel B	
OUT A	1	0	Output channel A	
OUT B	7	0	Output channel B	
V-	4	_	legative supply	
V+	8	_	Positive supply	

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7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
Committee	\(\lambda \)	Single-supply		40	
Supply voltage	$V_{S} = (V+) - (V-)$	Dual-supply		±20	V
	Voltage	Common-mode	(V-) - 0.5	(V+) + 0.5	V
Signal input pins		Differential		(V+) - (V-) + 0.2	
	Current			±10	mA
Output short circuit (2)			Continuous	Continuous	
	Operating, T _A		-55	150	
Temperature	Junction, T _J			150	°C
	Storage, T _{stg}		-65	150	

⁽¹⁾ Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±4000	V	
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	±1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
Supply voltage, $V_S = (V+) - (V-)$	Single-supply	4.5	36	V
	Dual-supply	±2.25	±18	
Specified temperature		-40	125	°C

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⁽²⁾ Short-circuit to ground, one amplifier per package.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.4 Thermal Information: OPA189

			OPA189			
	THERMAL METRIC ⁽¹⁾	D (SOIC)	DGK (VSSOP)	DBV (SOT)	UNIT	
		8 PINS	8 PINS	5 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	122.0	166.4	134.5	°C/W	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	57.6	54.2	90.5	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	67.3	87.9	41.9	°C/W	
Ψ_{JT}	Junction-to-top characterization parameter	12.7	5.5	22.5	°C/W	
Ψ_{JB}	Junction-to-board characterization parameter	66.2	86.4	41.6	°C/W	
R ₀ JC(bot)	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	°C/W	

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

7.5 Thermal Information: OPA2189

		OP.		
THERMAL METRIC ⁽¹⁾		D (SOIC)	DGK (VSSOP)	UNIT
		8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	115.7	150.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	51.1	43.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	60.8	71.4	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	9.8	2.9	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	59.7	70	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

Product Folder Links: OPA189 OPA2189



7.6 Electrical Characteristics

at $T_A = 25$ °C, $V_{CM} = V_{OUT} = V_S / 2$, and $R_{LOAD} = 10 \text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted)

	PARAMETER	TEST CONDIT	TONS	MIN	TYP	MAX	UNIT	
OFFSET \	VOLTAGE							
	Input offset voltage,				±0.4	±3		
.,	OPA189	$T_A = -40$ °C to 125°C				±4	μV	
Vos	Input offset voltage,				±1.5	±5	μV	
	OPA2189ID	$T_A = -40$ °C to 125°C			±8	μV		
	Input offset voltage drift, OPA189	$T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$			±0.005	±0.02	μV/°C	
dV _{OS} /dT	Input offset voltage drift,	$T_A = -0$ °C to 85°C			±0.007	±0.03	μV/°C	
	OPA2189ID	$T_A = -40$ °C to 125°C			±0.01	±0.05	μV/°C	
PSRR	Power-supply rejection ratio	$T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$			±0.005	±0.05	μV/V	
INPUT BI	AS CURRENT							
					±70	±300	pA	
	Input bias current, OPA189		$T_A = 0$ °C to 85°C			±1	ъ^	
		Z _{IN} = 100 kΩ 500 pF	$T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$			±10	nA	
I _B		Z _{IN} = 100 kt2 500 pF			±70	±300	5 nA	
	Input bias current, OPA2189		$T_A = 0$ °C to 85°C			±1.5		
			$T_A = -40$ °C to 125°C			±10		
	Input offset current, OPA189				±140	:140 ±600		
			$T_A = 0$ °C to 85°C			±1.6	nA	
		7 - 100 kO 500 pE	$T_A = -40$ °C to 125°C			±3		
los		$Z_{IN} = 100 \text{ k}\Omega \parallel 500 \text{ pF}$			±140	±600	pΑ	
	Input offset current, OPA2189		$T_A = 0$ °C to 85°C			±2.5	nA	
					±5	IIA		
NOISE								
- Input voltage noise	f = 0.1 Hz to 10 Hz		17		nV_{RMS}			
En	Input voltage noise	1 = 0.1112 to 10112			0.1		μV_{PP}	
	Input voltage noise density	f = 10 Hz			5.2			
Δ.		f = 100 Hz			5.2		nV/√ Hz	
e _n		f = 1 kHz			5.2		110/ 1112	
		f = 10 kHz			5.2			
i _n	Input current noise density	f = 1 kHz		165		fA/√Hz		
INPUT VC	DLTAGE							
V_{CM}	Common-mode voltage range			(V-) - 0.1		(V+) - 2.5	V	
CMRR		(//) (1)/(// (0/1) 25)/	$V_S = \pm 2.25 \text{ V}$	120	140			
	Common-mode rejection	$(V-) - 0.1 \ V \le V_{CM} \le (V+) - 2.5 \ V$	V _S = ±18 V	146	168		dB	
	ratio	$(V-) - 0.1 V \le V_{CM} \le (V+) - 2.5 V$	V _S = ±18 V	120			UD	
		$T_A = -40$ °C to 125°C	V _S = ±2.25 V	110				
INPUT IM	PEDANCE							
Z _{id}	Differential input impedance				0.1 5.5		GΩ pF	
z _{ic}	Common-mode input impedance				60 1.7		TΩ pF	

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Electrical Characteristics (continued)

at T_A = 25°C, V_{CM} = V_{OUT} = V_S / 2, and R_{LOAD} = 10 k Ω connected to V_S / 2 (unless otherwise noted)

	PARAMETER	TEST CONDIT	IONS	MIN	TYP	MAX	UNIT	
OPEN-LC	OOP GAIN							
A _{OL}			$(V-) + 0.3 V < V_O < (V+) - 0.3 V,$ $R_{LOAD} = 10 k\Omega$	150	170			
		V .40 V	$ \begin{aligned} &(V-) + 0.3 \ V < V_O < \\ &(V+) - 0.3 \ V, \\ &R_{LOAD} = 10 \ k\Omega, \\ &T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C} \\ &(V-) + 0.6 \ V < V_O < \\ &(V+) - 0.6 \ V, \\ &R_{LOAD} = 2 \ k\Omega \end{aligned} $				чD	
	Open-loop voltage gain	V _S = ±18 V			170		dB	
			$(V-) + 0.6 V < V_O < (V+) - 0.6 V,$ $R_{LOAD} = 2 k\Omega,$ $R_{LOAD} = 0.0000000000000000000000000000000000$	140	140			
FREQUE	NCY RESPONSE							
UGB	Unity-gain Bandwith	A _V = 1			8		MHz	
GBW	Gain-bandwith Product	A _V = 1000			14		IVITZ	
SR	Slew rate	G = 1, 10-V step			20		V/µs	
THD+N	Total harmonic distortion + noise	G = 1, f = 1 kHz, V _O = 3.5 V _{RMS}		0	.00006%			
	Cranatalle	OPA2189ID, at dc			150		dB	
	Crosstalk	OPA2189ID, f = 100 kHz		120			uБ	
t _S Settling time	Sottling time	To 0.1%	0.8					
	Settling time	To 0.01%		1.1		μs		
t _{OR}	Overload recovery time	$V_{IN} \times G = V_{S}$			320		ns	
OUTPUT								
	Voltage output swing from rail		No load		5	15		
		Positive rail	$R_{LOAD} = 10 \text{ k}\Omega$		20	110		
			$R_{LOAD} = 2 k\Omega$		80			
Vo			No load		5	15	mV	
		Negative rail	$R_{LOAD} = 10 \text{ k}\Omega$		20	110		
			$R_{LOAD} = 2 k\Omega$		80	500		
		$T_A = -40$ °C to 125°C, both rails, R_{LOA}	_{AD} = 10 kΩ		20	120		
I _{SC}	Short-circuit current				±65		mA	
C _{LOAD}	Capacitive load drive	See Small-Signal Overshoot vs Capa	acitive Load					
Z _O	Open-loop output impedance	f = 1 MHz, I _O = 0 A, see Open-Loop Frequency			380		Ω	
POWER S	SUPPLY					1		
IQ	Quiescent current per amplifier	$V_S = \pm 2.25 \text{ V to } \pm 18 \text{ V (}V_S = 4.5 \text{ V to } 36 \text{ V)}$	$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } 125^{\circ}C$		1.3	1.7	mA	
TEMPER		1 '	. _A = 10 0 10 120 0			1.0		
	Specified range			-40		+125	°C	
T _A	Specified range			-40		T120	C	

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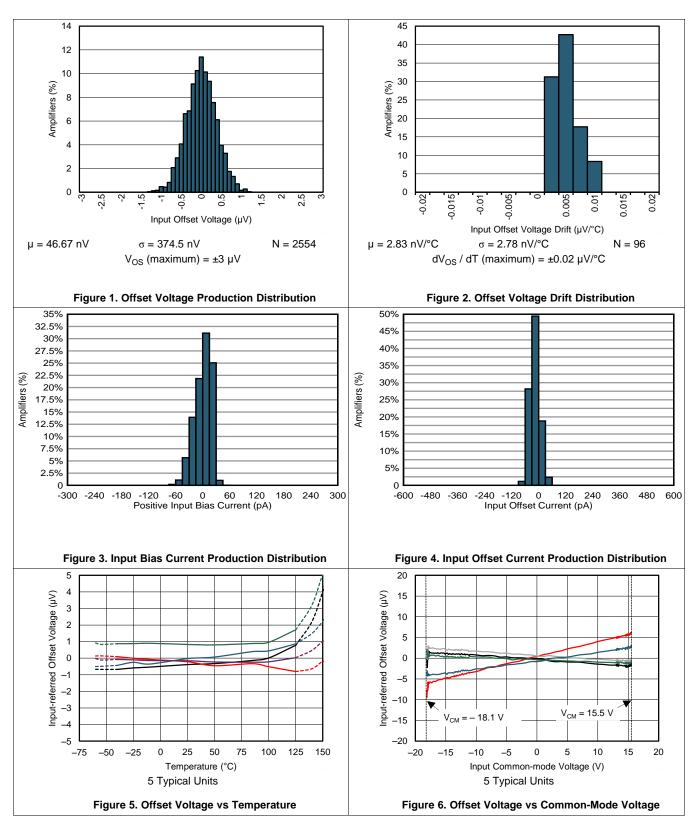
7.7 Typical Characteristics

Table 1. Typical Characteristic Graphs

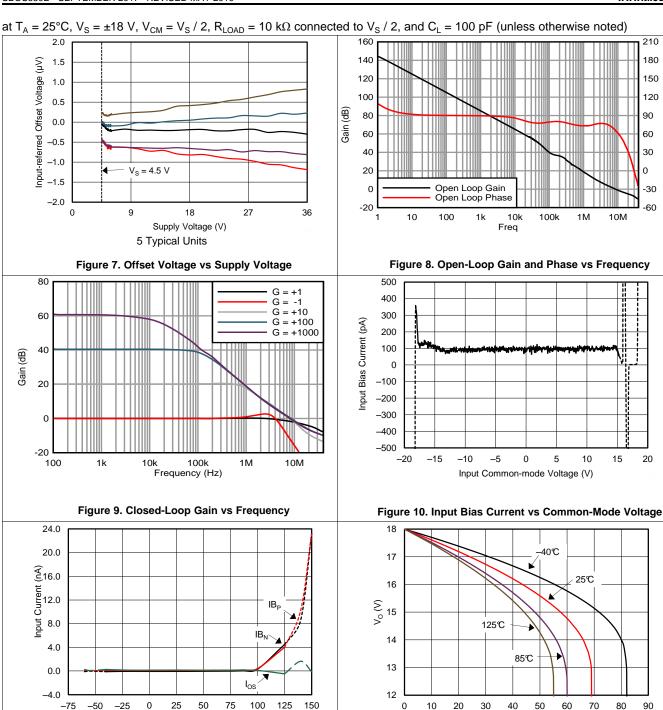
DESCRIPTION	FIGURE
Offset Voltage Production Distribution	Figure 1
Offset Voltage Drift Distribution From –40°C to 125°C	Figure 2
Input Bias Current Production Distribution	Figure 3
Input Offset Current Production Distribution	Figure 4
Offset Voltage vs Temperature	Figure 5
Offset Voltage vs Common-Mode Voltage	Figure 6
Offset Voltage vs Supply Voltage	Figure 7
Open-Loop Gain and Phase vs Frequency	Figure 8
Closed-Loop Gain vs Frequency	Figure 9
Input Bias Current vs Common-Mode Voltage	Figure 9
Input Bias Current and Offset vs Temperature	Figure 12
Output Voltage Swing vs Output Current (Sourcing)	Figure 12
Output Voltage Swing vs Output Current (Sinking)	Figure 13
CMRR and PSRR vs Frequency	Figure 14
CMRR vs Temperature	Figure 15
PSRR vs Temperature	Figure 16
0.1-Hz to 10-Hz Voltage Noise	Figure 17
Input Voltage Noise Spectral Density vs Frequency	Figure 18
THD+N Ratio vs Frequency	Figure 19
THD+N vs Output Amplitude	Figure 20
Quiescent Current vs Supply Voltage	Figure 21
Quiescent Current vs Temperature	Figure 22
Open-Loop Gain vs Temperature (10-kΩ)	Figure 23
Open-Loop Gain vs Temperature (2-kΩ)	Figure 24
Open-Loop Output Impedance vs Frequency	Figure 25
Small-Signal Overshoot vs Capacitive Load (10-mV Step)	Figure 26
No Phase Reversal	Figure 27
Positive Overload Recovery	Figure 28
Negative Overload Recovery	Figure 29
Small-Signal Step Response (10-mV Step)	Figure 30, Figure 31
Large-Signal Step Response (10-V Step)	Figure 32, Figure 33
Settling Time	Figure 34
Short-Circuit Current vs Temperature	Figure 35
Maximum Output Voltage vs Frequency	Figure 36
EMIRR vs Frequency	Figure 37
OPA189 Long-Term Drift	Figure 38
OPA2189 Long-Term Drift	Figure 39
Channel Separation	Figure 40
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Temperature (°C)

Figure 11. Input Bias Current and Offset vs Temperature

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 I_{O} (mA)

Figure 12. Output Voltage Swing vs Output Current

Sourcing





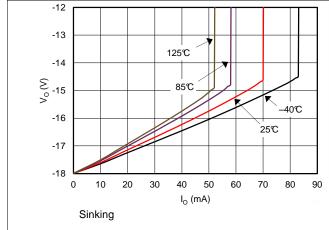


Figure 13. Output Voltage Swing vs Output Current

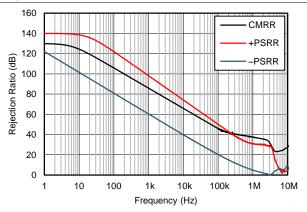


Figure 14. CMRR and PSRR vs Frequency

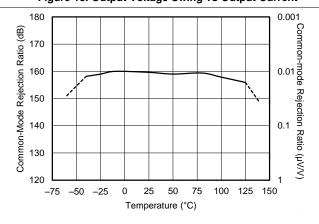


Figure 15. CMRR vs Temperature

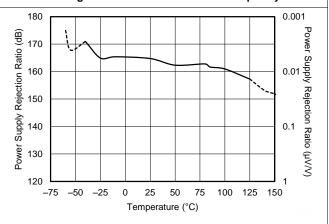


Figure 16. PSRR vs Temperature

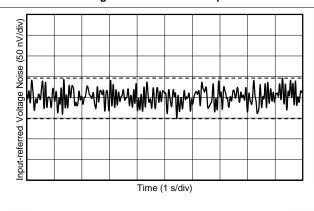


Figure 17. 0.1-Hz to 10-Hz Voltage Noise

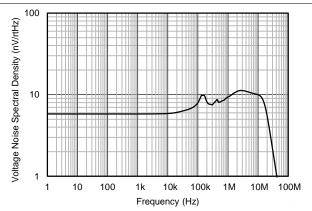
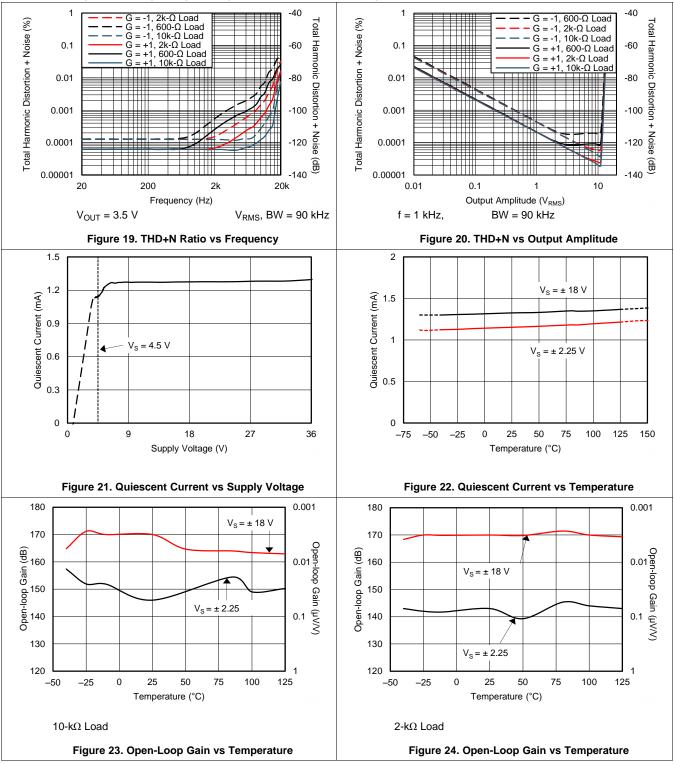
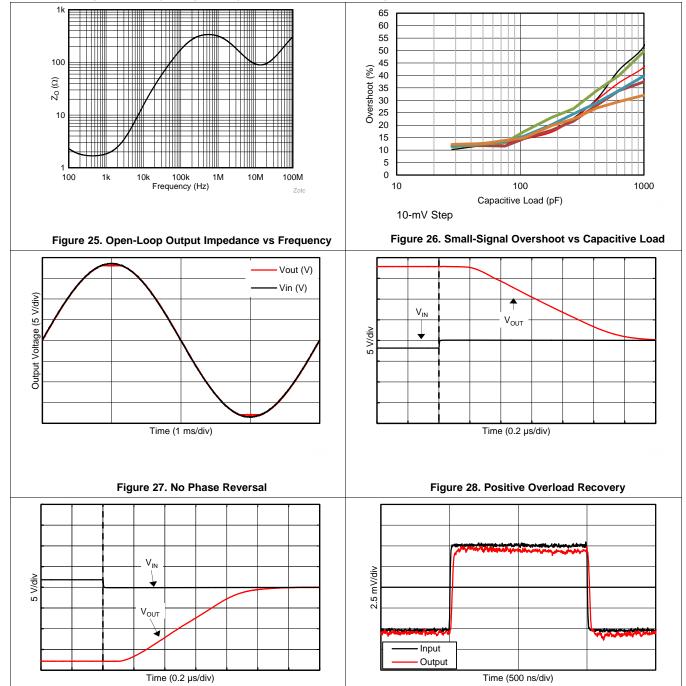


Figure 18. Input Voltage Noise Spectral Density vs Frequency









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Figure 29. Negative Overload Recovery

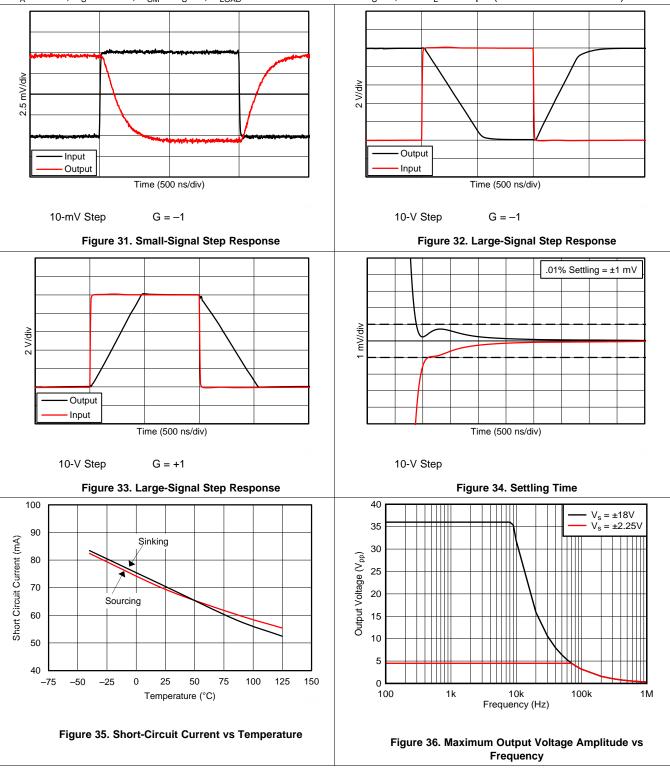
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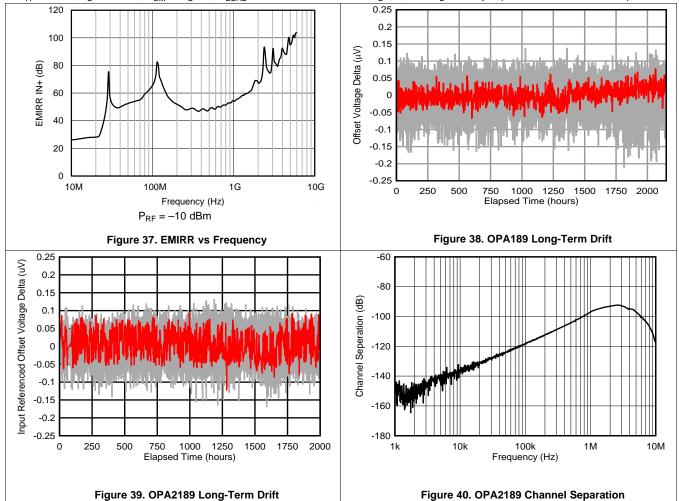
Figure 30. Small-Signal Step Response

10-mV Step











8 Detailed Description

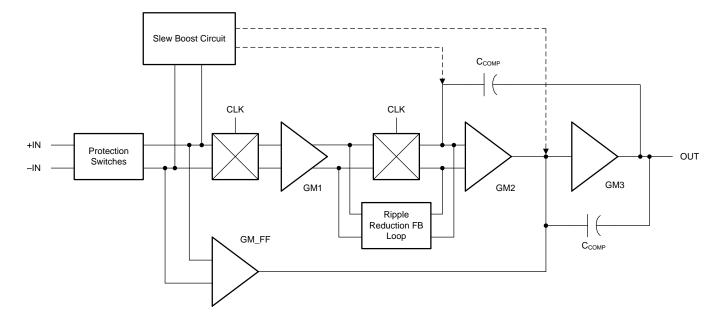
8.1 Overview

The OPAx189 operational amplifier combines precision offset and drift with excellent overall performance, making the device well-suited for many precision applications. The precision offset drift of only 0.005 μ V/°C provides stability over the entire temperature range. In addition, this device offers excellent linear performance with high CMRR, PSRR, and A_{OL}. As with all amplifiers, applications with noisy or high-impedance power supplies require decoupling capacitors close to the device pins. In most cases, 0.1- μ F capacitors are adequate. See *Layout Guidelines* for details and layout example.

The OPAx189 is part of a family of zero-drift, MUX-friendly, rail-to-rail output operational amplifiers. These devices operate from 4.5 V to 36 V, are unity-gain stable, and are suitable for a wide range of general-purpose and precision applications. The zero-drift architecture provides ultra-low input offset voltage and near-zero input offset voltage drift over temperature and time. This choice of architecture also offers outstanding ac performance, such as ultra-low broadband noise, zero flicker noise, and outstanding distortion performance when operating below the chopper frequency.

8.2 Functional Block Diagram

The Functional Block Diagram shows a representation of the proprietary OPAx189 architecture.





8.3 Feature Description

The OPAx189 series of op amps can be used with single or dual supplies from an operating range of $V_S = 4.5 \text{ V}$ (± 2.25 V) up to $V_S = 36$ V (± 18 V). These devices do not require symmetrical supplies; they only require a 4.5 (±2.25 V). For V_{S} supply voltage of V less than ±2.5 common-mode input range does not include midsupply. Supply voltages higher than 40 V can permanently damage the device; see the Absolute Maximum Ratings table for details. Key parameters are given over the specified temperature range, $T_A = -40^{\circ}$ C to +125°C, in *Electrical Characteristics*. Key parameters that vary over the supply voltage, temperature range, or frequency are shown in *Typical Characteristics*.

The OPAx189 is unity-gain stable and free from unexpected output phase reversal. This device uses a proprietary, periodic autocalibration technique to provide low input offset voltage and very low input offset voltage drift over time and temperature. For lowest offset voltage and precision performance, optimize circuit layout and mechanical conditions. Avoid temperature gradients that create thermoelectric (Seebeck) effects in the thermocouple junctions formed from connecting dissimilar conductors. Cancel these thermally-generated potentials by ensuring they are equal on both input pins. Other layout and design considerations include:

- Use low thermoelectric-coefficient conditions (avoid dissimilar metals).
- Thermally isolate components from power supplies or other heat sources.
- Shield operational amplifier and input circuitry from air currents, such as cooling fans.

Follow these guidelines to reduce the likelihood of junctions being at different temperatures, which may cause thermoelectric voltages of 0.1 μ V/°C or higher, depending on the materials used. See *Layout Guidelines* for details and layout example.

8.3.1 Operating Characteristics

The OPAx189 is specified for operation from 4.5 V to 36 V (±2.25 V to ±18 V). Many specifications apply from -40°C to +125°C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the *Typical Characteristics* section.

8.3.2 Phase-Reversal Protection

The OPAx189 has an internal phase-reversal protection. Many op amps exhibit a phase reversal when the input is driven beyond the linear common-mode range. This condition is most often encountered in noninverting circuits when the input is driven beyond the specified common-mode voltage range, causing the output to reverse into the opposite rail. The OPAx189 input prevents phase reversal with excessive common-mode voltage. Instead, the output limits into the appropriate rail. This performance is shown in Figure 41.

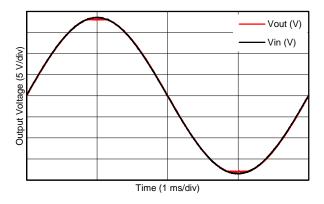


Figure 41. No Phase Reversal

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Feature Description (continued)

8.3.3 Input Bias Current Clock Feedthrough

Zero-drift amplifiers such as the OPAx189 use switching on the inputs to correct for the intrinsic offset and drift of the amplifier. Charge injection from the integrated switches on the inputs can introduce short transients in the input bias current of the amplifier. The extremely short duration of these pulses prevents the pulses from amplifying, however the pulses may be coupled to the output of the amplifier through the feedback network. The most effective method to prevent transients in the input bias current from producing additional noise at the amplifier output is to use a low-pass filter such as an RC network.

8.3.4 EMI Rejection

The OPAx189 uses integrated electromagnetic interference (EMI) filtering to reduce the effects of EMI interference from sources such as wireless communications and densely-populated boards with a mix of analog signal chain and digital components. EMI immunity can be improved with circuit design techniques; the OPAx189 benefits from these design improvements. Texas Instruments has developed the ability to accurately measure and quantify the immunity of an operational amplifier over a broad frequency spectrum extending from 10 MHz to 6 GHz. Figure 42 shows the results of this testing on the OPAx189. Table 2 lists the EMIRR +IN values for the OPAx189 at particular frequencies commonly encountered in real-world applications. Applications listed in Table 2 may be centered on or operated near the particular frequency shown. Detailed information can also be found in *EMI Rejection Ratio of Operational Amplifiers* (SBOA128), available for download from www.ti.com.

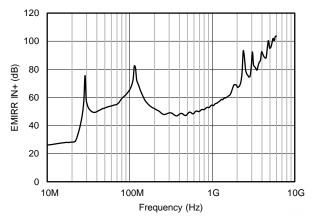


Figure 42. EMIRR Testing

Table 2. OPAx189 EMIRR IN+ for Frequencies of Interest

FREQUENCY	APPLICATION AND ALLOCATION	EMIRR IN+
400 MHz	Mobile radio, mobile satellite, space operation, weather, radar, ultra-high frequency (UHF) applications	48.4 dB
900 MHz	Global system for mobile communications (GSM) applications, radio communication, navigation, GPS (to 1.6 GHz), GSM, aeronautical mobile, UHF applications	52.8 dB
1.8 GHz	GSM applications, mobile personal communications, broadband, satellite, L-band (1 GHz to 2 GHz)	69.1 dB
2.4 GHz	802.11b, 802.11g, 802.11n, Bluetooth [®] , mobile personal communications, industrial, scientific and medical (ISM) radio band, amateur radio and satellite, S-band (2 GHz to 4 GHz)	88.9 dB
3.6 GHz	Radiolocation, aero communication and navigation, satellite, mobile, S-band	82.5 dB
5 GHz	802.11a, 802.11n, aero communication and navigation, mobile communication, space and satellite operation, C-band (4 GHz to 8 GHz)	95.5 dB

Product Folder Links: OPA189 OPA2189



The electromagnetic interference (EMI) rejection ratio, or EMIRR, describes the EMI immunity of operational amplifiers. An adverse effect that is common to many op amps is a change in the offset voltage as a result of RF signal rectification. An op amp that is more efficient at rejecting this change in offset as a result of EMI has a higher EMIRR and is quantified by a decibel value. Measuring EMIRR can be performed in many ways, but this section provides the EMIRR +IN, which specifically describes the EMIRR performance when the RF signal is applied to the noninverting input pin of the op amp. In general, only the noninverting input is tested for EMIRR for the following three reasons:

- Op amp input pins are known to be the most sensitive to EMI, and typically rectify RF signals better than the supply or output pins.
- The noninverting and inverting op amp inputs have symmetrical physical layouts and exhibit nearly matching EMIRR performance
- EMIRR is more simple to measure on noninverting pins than on other pins because the noninverting input terminal can be isolated on a PCB. This isolation allows the RF signal to be applied directly to the noninverting input terminal with no complex interactions from other components or connecting PCB traces.

High-frequency signals conducted or radiated to any pin of the operational amplifier may result in adverse effects, as the amplifier would not have sufficient loop gain to correct for signals with spectral content outside the bandwidth. Conducted or radiated EMI on inputs, power supply, or output may result in unexpected DC offsets, transient voltages, or other unknown behavior. Take care to properly shield and isolate sensitive analog nodes from noisy radio signals and digital clocks and interfaces.

The EMIRR +IN of the OPAx189 is plotted versus frequency as shown in Figure 42. If available, any dual and quad op amp device versions have nearly similar EMIRR +IN performance. The OPAx189 unity-gain bandwidth is 14 MHz. EMIRR performance below this frequency denotes interfering signals that fall within the op amp bandwidth.

8.3.5 EMIRR +IN Test Configuration

Figure 43 shows the circuit configuration for testing the EMIRR +IN. An RF source is connected to the op amp noninverting input terminal using a transmission line. The op amp is configured in a unity-gain buffer topology with the output connected to a low-pass filter (LPF) and a digital multimeter (DMM). A large impedance mismatch at the op amp input causes a voltage reflection; however, this effect is characterized and accounted for when determining the EMIRR IN+. The multimeter samples and measures the resulting DC offset voltage. The LPF isolates the multimeter from residual RF signals that may interfere with multimeter accuracy.

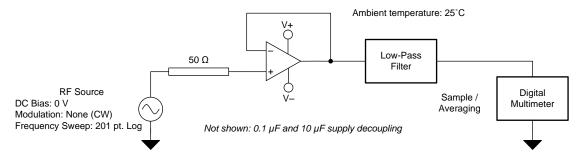


Figure 43. EMIRR +IN Test Configuration

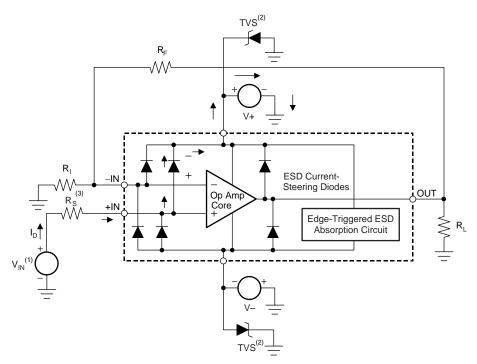
Product Folder Links: OPA189 OPA2189



8.3.6 Electrical Overstress

Designers often ask questions about the capability of an operational amplifier to withstand electrical overstress. These questions tend to focus on the device inputs, but may involve the supply voltage pins or even the output pin. Each of these different pin functions have electrical stress limits determined by the voltage breakdown characteristics of the particular semiconductor fabrication process and specific circuits connected to the pin. Additionally, internal electrostatic discharge (ESD) protection is built into these circuits to protect from accidental ESD events both before and during product assembly.

Having a good understanding of this basic ESD circuitry and the relevance to an electrical overstress event is helpful. See Figure 44 for an illustration of the ESD circuits contained in the OPAx189 (indicated by the dashed line area). The ESD protection circuitry involves several current-steering diodes connected from the input and output pins and routed back to the internal power-supply lines, where the diodes meet at an absorption device internal to the operational amplifier. This protection circuitry is intended to remain inactive during normal circuit operation.



- (1) $V_{IN} = V + + 500 \text{ mV}$
- (2) TVS: 40 V > V_{TVSBR (min)} > V+; where V_{TVSBR (min)} is the minimum specified value for the transient voltage suppressor breakdown voltage
- (3) Suggested value is approximately 5 $k\Omega$ in overvoltage conditions.

Figure 44. Equivalent Internal ESD Circuitry Relative to a Typical Circuit Application

An ESD event produces a short-duration, high-voltage pulse that is transformed into a short-duration, high-current pulse while discharging through a semiconductor device. The ESD protection circuits are designed to provide a current path around the operational amplifier core to prevent damage. The energy absorbed by the protection circuitry is then dissipated as heat.

When an ESD voltage develops across two or more amplifier device pins, current flows through one or more steering diodes. Depending on the path that the current takes, the absorption device may activate. The absorption device has a trigger or threshold voltage that is above the normal operating voltage of the OPAx189 but below the device breakdown voltage level. When this threshold is exceeded, the absorption device quickly activates and clamps the voltage across the supply rails to a safe level.



When the operational amplifier connects into a circuit (as shown in Figure 44), the ESD protection components are intended to remain inactive and do not become involved in the application circuit operation. However, circumstances may arise where an applied voltage exceeds the operating voltage range of a given pin. Should this condition occur, there is a risk that some internal ESD protection circuits may be biased on, and conduct current. Any such current flow occurs through steering-diode paths and rarely involves the absorption device.

Figure 44 shows a specific example where the input voltage (V_{IN}) exceeds the positive supply voltage (V+) by 500 mV or more. Much of what happens in the circuit depends on the supply characteristics. If V+ can sink the current, one of the upper input steering diodes conducts and directs current to +V_S. Excessively high current levels can flow with increasingly higher V_{IN}. As a result, the data sheet specifications recommend that applications limit the input current to 10 mA.

If the supply is not capable of sinking the current, V_{IN} may begin sourcing current to the operational amplifier, and then take over as the source of positive supply voltage. The danger in this case is that the voltage can rise to levels that exceed the operational amplifier absolute maximum ratings.

Another common question involves what happens to the amplifier if an input signal is applied to the input while the power supplies V+ or V- are at 0 V. Again, this question depends on the supply characteristic while at 0 V, or at a level below the input signal amplitude. If the supplies appear as high impedance, then the operational amplifier supply current may be supplied by the input source through the current-steering diodes. This state is not a normal bias condition; the amplifier most likely does not operate normally. If the supplies are low impedance, then the current through the steering diodes can become guite high. The current level depends on the ability of the input source to deliver current, and any resistance in the input path.

If there is any uncertainty about the ability of the supply to absorb this current, external zener diodes must be added to the supply pins, as shown in Figure 44. The zener voltage must be selected such that the diode does not turn on during normal operation. However, the zener voltage must be low enough so that the zener diode conducts if the supply pin begins to rise above the safe operating supply voltage level.

8.3.7 MUX-Friendly Inputs

The OPAx189 features a proprietary input stage design that allows an input differential voltage to be applied while maintaining high input impedance. Typically, high-voltage CMOS or bipolar-junction input amplifiers feature anti-parallel diodes that protect input transistors from large V_{GS} voltages that may exceed the semiconductor process maximum and permanently damage the device. Large V_{GS} voltages can be forced when applying a large input step, switching between channels, or attempting to use the amplifier as a comparator.

OPAx189 solves these problems with a switched-input technique that prevents large input bias currents when large differential voltages are applied. This solves many issues seen in switched or multiplexed applications, where large disruptions to RC filtering networks are caused by fast switching between large potentials. OPAx189 offers outstanding settling performance due to these design innovations and built-in slew rate boost and wide bandwidth. The OPAx189 can also be used as a comparator. Differential and common-mode Absolute Maximum Ratings still apply relative to the power supplies.

Product Folder Links: OPA189 OPA2189



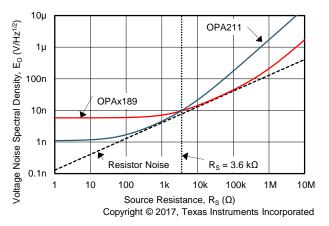
8.3.8 Noise Performance

Figure 45 shows the total circuit noise for varying source impedances with the operational amplifier in a unity-gain configuration (with no feedback resistor network and therefore no additional noise contributions). The OPAx189 and OPA211 are shown with total circuit noise calculated. The op amp itself contributes both a voltage noise component and a current noise component. The voltage noise is commonly modeled as a time-varying component of the offset voltage. The current noise is modeled as the time-varying component of the input bias current and reacts with the source resistance to create a voltage component of noise. Therefore, the lowest noise op amp for a given application depends on the source impedance. For low source impedance, current noise is negligible, and voltage noise generally dominates. The OPAx189 family has both low voltage noise and low current noise because of the CMOS input of the op amp. As a result, the current noise contribution of the OPAx189 series is negligible for any practical source impedance, which makes this device the better choice for applications with high source impedance.

The equation in Figure 45 shows the calculation of the total circuit noise, with these parameters:

- e_n = voltage noise
- i_n = current noise
- R_S = source impedance
- $k = Boltzmann's constant = 1.38 \times 10^{-23} J/K$
- T = temperature in degrees Kelvin (K)

For more details on calculating noise, see Basic Noise Calculations.



 $R_S = 3.6 \text{ k}\Omega$ is indicated in Figure 45.

This is the source impedance above which OPAx189 is a lower noise option than the OPA211.

Figure 45. Noise Performance of the OPAx189 and OPA211 in Unity-Gain Buffer Configuration

8.3.9 Basic Noise Calculations

Low-noise circuit design requires careful analysis of all noise sources. External noise sources can dominate in many cases; consider the effect of source resistance on overall op amp noise performance. Total noise of the circuit is the root-sum-square combination of all noise components.

The resistive portion of the source impedance produces thermal noise proportional to the square root of the resistance. This function is plotted in Figure 45. The source impedance is usually fixed; consequently, select the op amp and the feedback resistors to minimize the respective contributions to the total noise.

Figure 46 illustrates both noninverting (A) and inverting (B) op amp circuit configurations with gain. In circuit configurations with gain, the feedback network resistors also contribute noise. In general, the current noise of the op amp reacts with the feedback resistors to create additional noise components. However, the extremely low current noise of the OPAx189 means that the current noise contribution can be neglected.

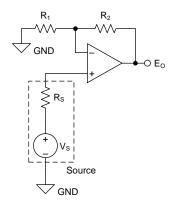
The feedback resistor values can generally be chosen to make these noise sources negligible. Low impedance feedback resistors load the output of the amplifier. The equations for total noise are shown for both configurations.

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(A) Noise in Noninverting Gain Configuration

Noise at the output is given as E_{O} , where



(1)
$$E_0 = \left(1 + \frac{R_2}{R_1}\right) \cdot \sqrt{(e_S)^2 + (e_N)^2 + \left(e_{R_1 \parallel R_2}\right)^2 + (i_N \cdot R_S)^2 + \left(i_N \cdot \left[\frac{R_1 \cdot R_2}{R_1 + R_2}\right]\right)^2} \quad [V_{RMS}]$$

(2)
$$e_S = \sqrt{4 \cdot k_B \cdot T(K) \cdot R_S} \quad \left[\frac{V}{\sqrt{Hz}} \right]$$
 Thermal noise of R_S

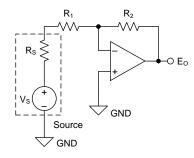
(3)
$$e_{R_1 \parallel R_2} = \sqrt{4 \cdot k_B \cdot T(K) \cdot \left[\frac{R_1 \cdot R_2}{R_1 + R_2}\right]} \quad \left[\frac{V}{\sqrt{Hz}}\right]$$
 Thermal noise of R₁ || R₂

(4)
$$k_B = 1.38065 \cdot 10^{-23}$$
 $\left[\frac{J}{K}\right]$ Boltzmann Constant

(5)
$$T(K) = 237.15 + T(^{\circ}C)$$
 [K] Temperature in kelvins

(B) Noise in Inverting Gain Configuration

Noise at the output is given as Eo, where



(6)
$$E_0 = \left(1 + \frac{R_2}{R_S + R_1}\right) \cdot \sqrt{(e_N)^2 + \left(e_{R_1 + R_S \parallel R_2}\right)^2 + \left(i_N \cdot \left[\frac{(R_S + R_1) \cdot R_2}{R_S + R_1 + R_2}\right]\right)^2} \quad [V_{RMS}]$$

(7)
$$e_{R_1+R_S\parallel R_2} = \sqrt{4 \cdot k_B \cdot T(K) \cdot \left[\frac{(R_S+R_1) \cdot R_2}{R_S+R_1+R_2} \right]} \quad \left[\frac{V}{\sqrt{Hz}} \right]$$
 Thermal noise of (R₁ + R_S) || R₂

(8)
$$k_B = 1.38065 \cdot 10^{-23} \left[\frac{J}{K} \right]$$
 Boltzmann Constant

(9)
$$T(K) = 237.15 + T(^{\circ}C)$$
 [K] Temperature in kelvins

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- (1) e_n is the voltage noise spectral density of the amplifier. For the OPAx189 series of operational amplifiers, $e_n = 5.2 \text{ nV/} \sqrt{\text{Hz}}$ at 1 kHz.
- (2) i_n is the current noise spectral density of the amplifier. For the OPAx189 series of operational amplifiers, $i_n = 165 \text{ fA/} \sqrt{\text{Hz}}$ at 1 kHz.
- (3) For additional resources on noise calculations visit TI's Precision Labs Series.

Figure 46. Noise Calculation in Gain Configurations

8.4 Device Functional Modes

The OPAx189 has a single functional mode, and is operational when the power-supply voltage is greater than 4.5 V (±2.25 V). The maximum power supply voltage for the OPAx189 is 36 V (±18 V).



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

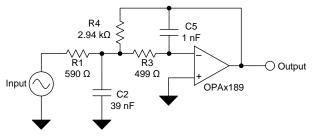
9.1 Application Information

The OPAx189 operational amplifier combines precision offset and drift with excellent overall performance, making the series ideal for many precision applications. The precision offset drift of only 0.005 μ V/°C provides stability over the entire temperature range. In addition, the device pairs excellent CMRR, PSRR, and A_{OL} dc performance with outstanding low-noise operation. As with all amplifiers, applications with noisy or high-impedance power supplies require decoupling capacitors close to the device pins. In most cases, 0.1- μ F capacitors are adequate.

The following application examples highlight only a few of the circuits where the OPAx189 can be used.

9.2 Typical Applications

9.2.1 25-kHz Low-Pass Filter



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Figure 47. 25-kHz Low-Pass Filter

9.2.1.1 Design Requirements

Low-pass filters are commonly employed in signal processing applications to reduce noise and prevent aliasing. The OPAx189 devices are ideally suited to construct high-speed, high-precision active filters. Figure 47 shows a second-order, low-pass filter commonly encountered in signal processing applications.

Use the following parameters for this design example:

- Gain = 5 V/V (inverting gain)
- Low-pass cutoff frequency = 25 kHz
- Second-order Chebyshev filter response with 3-dB gain peaking in the passband

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9.2.1.2 Detailed Design Procedure

The infinite-gain multiple-feedback circuit for a low-pass network function is shown in Figure 47. Use Equation 1 to calculate the voltage transfer function.

$$\frac{Output}{Input}(s) = \frac{-1/R_1R_3C_2C_5}{s^2 + (s/C_2)(1/R_1 + 1/R_3 + 1/R_4) + 1/R_3R_4C_2C_5}$$
 (1)

This circuit produces a signal inversion. For this circuit, the gain at dc and the low-pass cutoff frequency are calculated by Equation 2:

Gain =
$$\frac{R_4}{R_1}$$

 $f_C = \frac{1}{2\pi} \sqrt{(1/R_3 R_4 C_2 C_5)}$ (2)

Software tools are readily available to simplify filter design. WEBENCH® Filter Designer is a simple, powerful, and easy-to-use active filter design program. The WEBENCH® Filter Designer lets the user create optimized filter designs using a selection of TI operational amplifiers and passive components from TI's vendor partners.

Available as a web based tool from the WEBENCH Design Center, WEBENCH Filter Designer allows board-level designers to create, optimize, and simulate complete multistage active filter solutions within minutes.

9.2.1.3 Application Curve

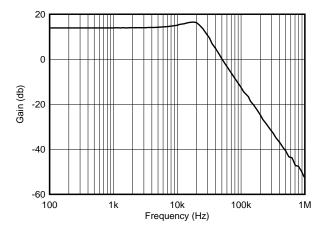


Figure 48. OPAx189 Second-Order, 25-kHz, Chebyshev, Low-Pass Filter

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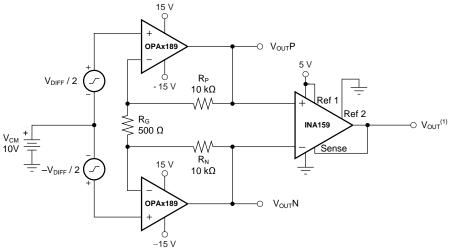


9.2.2 Discrete INA + Attenuation for ADC With 3.3-V Supply

NOTE

The TINA-TI files shown in the following sections require that either the TINA software (from DesignSoft™) or TINA-TI software be installed. Download the free TINA-TI software from the TINA-TI folder.

Figure 49 shows an example of how the OPAx189 is used as a high-voltage, high-impedance front-end for a precision, discrete instrumentation amplifier with attenuation. The INA159 provides the attenuation that allows this circuit to simply interface with 3.3-V or 5-V analog-to-digital converters (ADCs). Click the following link download the TINA-TI file: Discrete INA.



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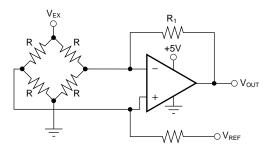
(1) $V_{OUT} = V_{DIFF} \times (41 / 5) + (Ref 1) / 2$.

Figure 49. Discrete INA + Attenuation for ADC With 3.3-V Supply



9.2.3 Bridge Amplifier

Figure 50 shows the basic configuration for a bridge amplifier. Click the following link to download the TINA-TI file: Bridge Amplifier Circuit.



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Figure 50. Bridge Amplifier

9.2.4 Low-Side Current Monitor

Figure 51 shows the OPAx189 configured in a low-side current-sensing application. The load current (I_{LOAD}) creates a voltage drop across the shunt resistor (R_{SHUNT}). This voltage is amplified by the OPAx189, with a gain of 201. In this example the load current is set from 0 A to 500 mA, which corresponds to an output voltage range from 0 V to 10 V. The output range can be adjusted by changing the shunt resistor or gain of the configuration. Click the following link to download the TINA-TI file: Current-Sensing Circuit.

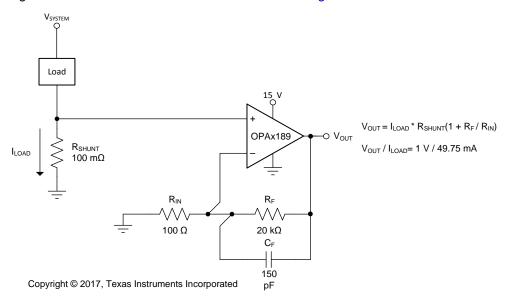


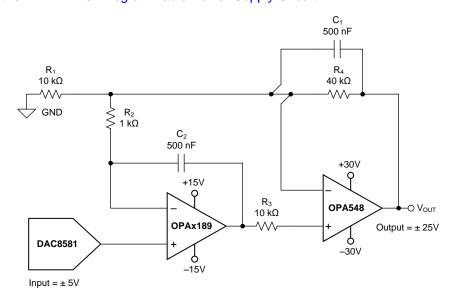
Figure 51. Low-Side Current Monitor

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9.2.5 Programmable Power Supply

Figure 52 shows the OPAx189 configured as a precision programmable power supply using the 16-bit, voltage output DAC8581 and the OPA548 high-current amplifier. This application amplifies the digital-to-analog converter (DAC) voltage by a value of five, and handles a large variety of capacitive and current loads. The OPAx189 in the front-end provides precision and low drift across a wide range of inputs and conditions. Click the following link to download the TINA-TI file: Programmable Power-Supply Circuit.

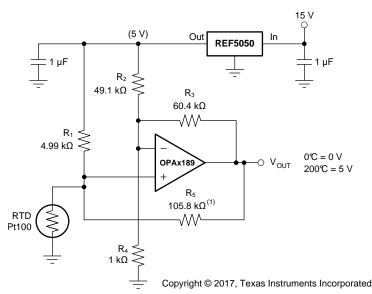


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Figure 52. Programmable Power Supply

9.2.6 RTD Amplifier With Linearization

See *Analog Linearization of Resistance Temperature Detectors* (SLYT442) for an in-depth analysis of Figure 53. Click the following link to download the TINA-TI file: RTD Amplifier with Linearization.



(1) R₅ provides positive-varying excitation to linearize output.

Figure 53. RTD Amplifier With Linearization

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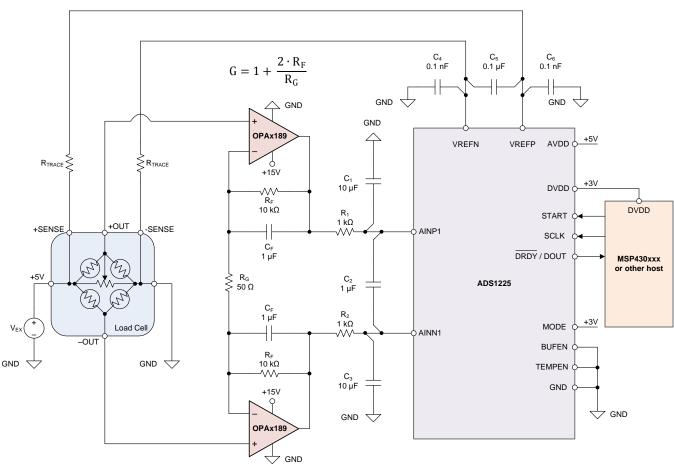


9.3 System Examples

9.3.1 24-Bit, Delta-Sigma, Differential Load Cell or Strain Gauge Sensor Signal Conditioning

OPAx189 is used in a 24-bit, differential load cell or strain gauge sensor signal conditioning system alongside the ADS1225. A pair of OPAx189 amplifiers are configured in a two-amp instrumentation amplifier (IA) configuration and are band-limited to reduce noise and allow heavy capacitive drive. The load cell is powered by an excitation voltage (denoted V_{EX}) of 5-V and provides a differential voltage proportional to force applied. The differential voltage can be quite small and both outputs are biased to V_{EX} / 2.

In this example the OPAx189 is employed here due to the excellent input offset voltage (0.4 μ V) and input offset voltage drift (0.005 μ V/°C), the low broadband noise (5.2 nV/ $\sqrt{\text{Hz}}$) and zero-flicker noise, and excellent linearity and high input impedance. The two-amp IA configuration removes the dc bias and amplifies the differential signal of interest and drives the 24-bit, delta-sigma ADS1225 analog-to-digital converter (ADC) for acquisition and conversion. The ADS1225 features a 100-SPS data rate, single-cycle settling, and simple conversion control with the dedicated START pin.



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Figure 54. 24-Bit, Differential Load Cell or Strain Gauge Sensor Signal Conditioning Schematic



10 Power Supply Recommendations

The OPAx189 is specified for operation from 4.5 V to 36 V (±2.25 V to ±18 V); many specifications apply from –40°C to +125°C. The *Typical Characteristics* presents parameters that can exhibit significant variance with regard to operating voltage or temperature.

CAUTION

Supply voltages larger than 40 V can permanently damage the device (see the *Absolute Maximum Ratings*).

Place 0.1- μ F bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see the *Layout* section.

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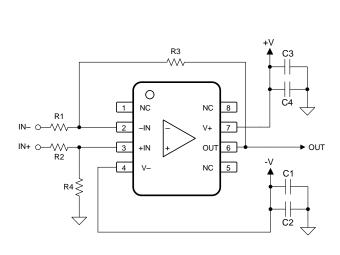
11 Layout

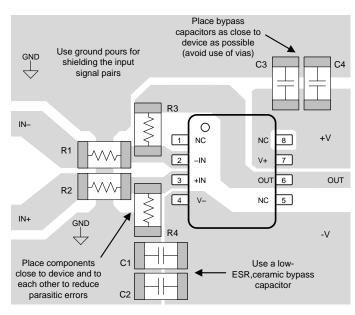
11.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and the op amp itself. Bypass capacitors reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
 - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close as possible to the device. A single bypass capacitor from V+ to ground is applicable for singlesupply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds paying attention to the flow of the ground current. For more detailed information, see *The PCB* is a component of op amp design.
- To reduce parasitic coupling, run the input traces as far away as possible from the supply or output traces. If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better as opposed to in parallel with the noisy trace.
- Place the external components as close as possible to the device. As illustrated in Figure 55, keeping RF and RG close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.
- For best performance, TI recommends cleaning the PCB following board assembly.
- Any precision integrated circuit may experience performance shifts due to moisture ingress into the
 plastic package. Following any aqueous PCB cleaning process, TI recommends baking the PCB
 assembly to remove moisture introduced into the device packaging during the cleaning process. A low
 temperature, post cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.

11.2 Layout Example





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Figure 55. Operational Amplifier Board Layout for Difference Amplifier Configuration



12 Device and Documentation Support

12.1 Device Support

12.1.1 Development Support

12.1.1.1 TINA-TI™ (Free Software Download)

TINA-TITM is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TITM is a free, fully-functional version of the TINATM software, preloaded with a library of macromodels in addition to a range of both passive and active models. TINA-TITM provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a free download from the Analog eLab Design Center, TINA-TITM offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic guick-start tool.

NOTE

These files require that either the TINA software (from DesignSoft™) or TINA-TI™ software be installed. Download the free TINA-TI™ software from the TINA-TI™ folder.

12.1.1.2 TI Precision Designs

TI Precision Designs are available online at http://www.ti.com/ww/en/analog/precision-designs/. TI Precision Designs are analog solutions created by TI's precision analog applications experts and offer the theory of operation, component selection, simulation, complete PCB schematic and layout, bill of materials, and measured performance of many useful circuits.

12.2 Documentation Support

12.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, Zero-drift Amplifiers: Features and Benefits application brief
- Texas Instruments, The PCB is a component of op amp design technical brief
- Texas Instruments, Operational amplifier gain stability, Part 3: AC gain-error analysis technical brief
- Texas Instruments, Operational amplifier gain stability, Part 2: DC gain-error analysis technical brief
- · Texas Instruments, Using infinite-gain, MFB filter topology in fully differential active filters technical brief
- Texas Instruments, Op Amp Performance Analysis application bulletin
- Texas Instruments, Single-Supply Operation of Operational Amplifiers application bulletin
- Texas Instruments, Tuning in Amplifiers application bulletin
- Texas Instruments, Shelf-Life Evaluation of Lead-Free Component Finishes application report
- Texas Instruments, Feedback Plots Define Op Amp AC Performance application bulletin
- Texas Instruments, EMI Rejection Ratio of Operational Amplifiers (With OPA333 and OPA333-Q1 as an Example) application report
- Texas Instruments, Analog linearization of resistance temperature detectors technical brief
- Texas Instruments, TI Precision Design TIPD102 High-Side Voltage-to-Current (V-I) Converter reference guide



12.3 Related Links

Table 3 lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 3. Related Links

PARTS	PARTS PRODUCT FOLDER		TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
OPA189	Click here	Click here	Click here	Click here	Click here	
OPA2189	Click here	Click here	Click here	Click here	Click here	

12.4 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on Alert me to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.5 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community T's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.6 Trademarks

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12.7 Electrostatic Discharge Caution

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.8 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





6-Feb-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
OPA189ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA189	Samples
OPA189IDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	1CTV	Samples
OPA189IDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	1CTV	Samples
OPA189IDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	1CS6	Samples
OPA189IDGKT	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	1CS6	Samples
OPA189IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA189	Samples
OPA2189ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	SN	Level-2-260C-1 YEAR	-40 to 125	OP2189	Samples
OPA2189IDGKR	PREVIEW	VSSOP	DGK	8	2500	TBD	Call TI	Call TI	-40 to 125		
OPA2189IDGKT	PREVIEW	VSSOP	DGK	8	250	TBD	Call TI	Call TI	-40 to 125		
OPA2189IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	SN	Level-2-260C-1 YEAR	-40 to 125	OP2189	Samples
POPA2189IDGKR	ACTIVE	VSSOP	DGK	8	2500	TBD	Call TI	Call TI	-40 to 125		Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

6-Feb-2020

- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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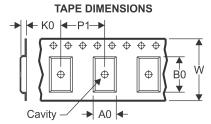
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 17-Apr-2020

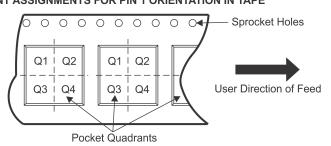
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA189IDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
OPA189IDBVT	SOT-23	DBV	5	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
OPA189IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA189IDGKT	VSSOP	DGK	8	250	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA189IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA2189IDR	SOIC	D	8	2500	330.0	12.8	6.4	5.2	2.1	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 17-Apr-2020

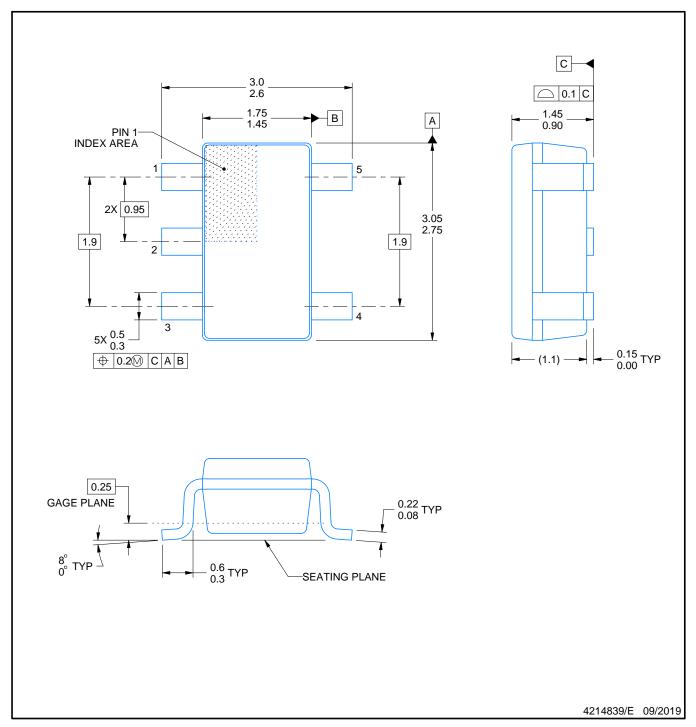


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
OPA189IDBVR	SOT-23	DBV	5	3000	213.0	191.0	35.0	
OPA189IDBVT	SOT-23	DBV	5	250	213.0	191.0	35.0	
OPA189IDGKR	VSSOP	DGK	8	2500	366.0	364.0	50.0	
OPA189IDGKT	VSSOP	DGK	8	250	366.0	364.0	50.0	
OPA189IDR	SOIC	D	8	2500	367.0	367.0	35.0	
OPA2189IDR	SOIC	D	8	2500	366.0	364.0	50.0	



SMALL OUTLINE TRANSISTOR

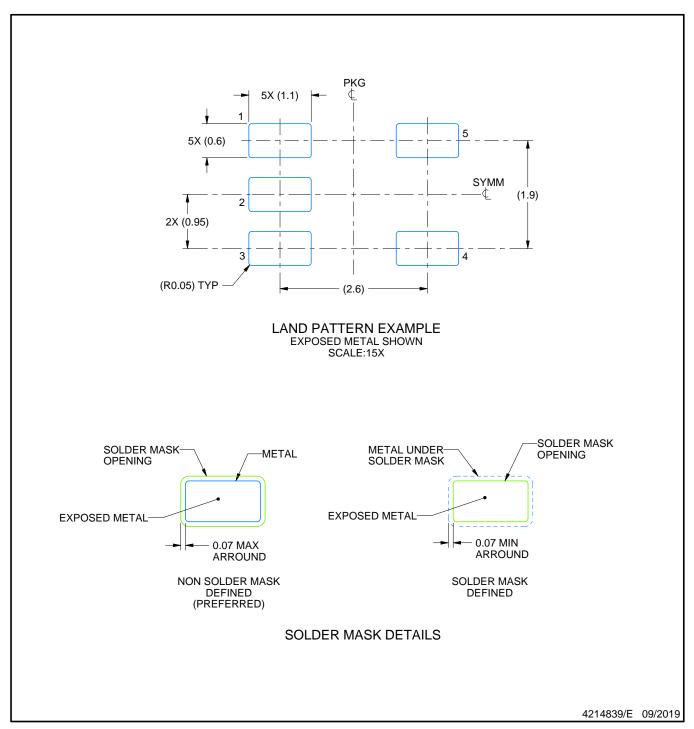


- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.



SMALL OUTLINE TRANSISTOR

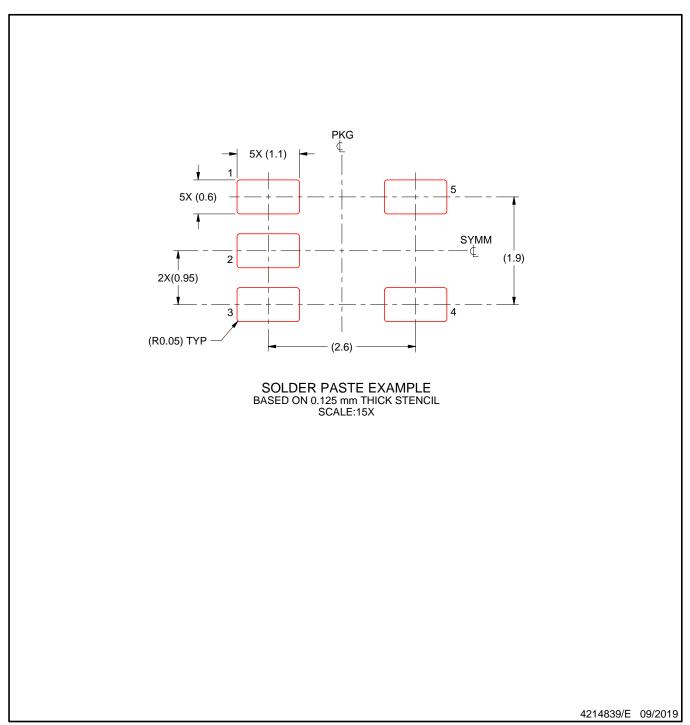


NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

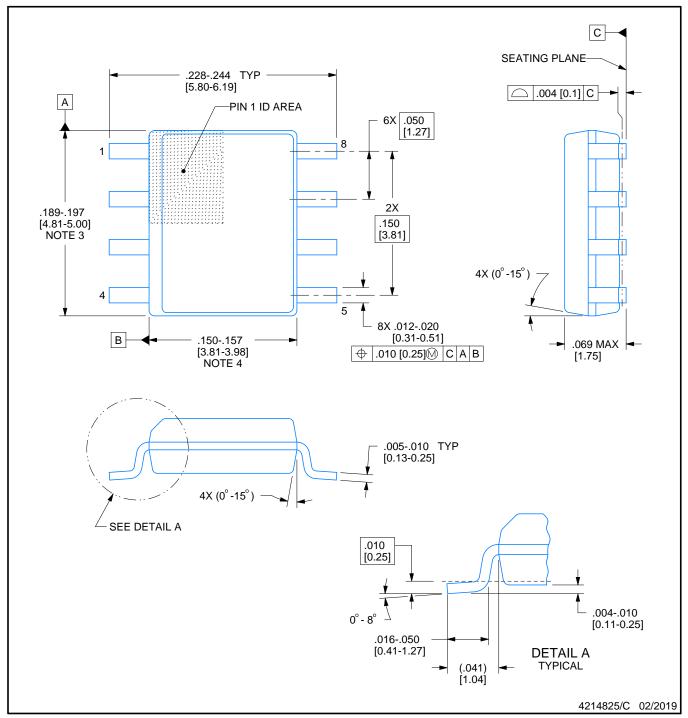


^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

^{8.} Board assembly site may have different recommendations for stencil design.



SMALL OUTLINE INTEGRATED CIRCUIT



- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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